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學 經 歷

姓 名：白 承 丘

性 別：男

生 日：民國六十九年十一月二日

地 址：彰化縣和美鎮詔安里福東路 102 巷 1 號

學 歷：國立成功大學電機工程學系(88.9~92.6)

國立交通大學光電工程研究所碩士班(92.9~94.6)

碩士班論文題目：主動式顯示器用複晶矽薄膜電晶體補償電路之研究

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著作目錄及發表論文

INTERNATIONAL CONFERENCE PAPERS

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